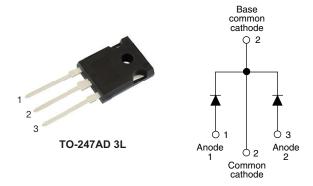


COMPLIANT

HALOGEN FREE

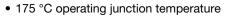
# Ultrafast Soft Recovery Diode, 2 x 30 A FRED Pt® Gen 4



| PRIMARY CHARACTERISTICS          |                    |  |  |  |  |
|----------------------------------|--------------------|--|--|--|--|
| I <sub>F(AV)</sub>               | 2 x 30 A           |  |  |  |  |
| $V_{R}$                          | 600 V              |  |  |  |  |
| V <sub>F</sub> at I <sub>F</sub> | 1.19 V             |  |  |  |  |
| t <sub>rr</sub> typ.             | See Recovery table |  |  |  |  |
| T <sub>J</sub> max.              | 175 °C             |  |  |  |  |
| Package                          | TO-247AD 3L        |  |  |  |  |
| Circuit configuration            | Common cathode     |  |  |  |  |

#### **FEATURES**

- Gen 4 FRED Pt® technology
- Low I<sub>RRM</sub> and reverse recovery charge
- · Very low forward voltage drop
- Polyimide passivated chip for high reliability standard





 Material categorization: for definitions of compliance please see <a href="https://www.vishay.com/doc?99912"><u>www.vishay.com/doc?99912</u></a>

#### **DESCRIPTION**

Gen 4 Fred technology, state of the art, ultralow  $V_F$ , soft switching optimized for Discontinuous (Critical) Mode (DCM) and IGBT F/W diode.

The minimized conduction loss, optimized stored charge and low recovery current minimize the switching losses and reduce power dissipation in the switching element and snubbers.

| ABSOLUTE MAXIMUM RATINGS                   |                                   |                                               |             |       |  |
|--------------------------------------------|-----------------------------------|-----------------------------------------------|-------------|-------|--|
| PARAMETER                                  | SYMBOL                            | TEST CONDITIONS                               | MAX.        | UNITS |  |
| Peak repetitive reverse voltage            | $V_{RRM}$                         |                                               | 600         | V     |  |
| Average rectified forward current          | I <sub>F(AV)</sub>                | T <sub>C</sub> = 131 °C                       | 30          | ۸     |  |
| Non-repetitive peak surge current, per leg | I <sub>FSM</sub>                  | $T_C = 25$ °C, $t_p = 8.3$ ms, half sine wave | 240         | А     |  |
| Operating junction and storage temperature | T <sub>J</sub> , T <sub>Stg</sub> |                                               | -55 to +175 | °C    |  |

| <b>ELECTRICAL SPECIFICATIONS</b> (T <sub>J</sub> = 25 °C unless otherwise specified) |                                  |                                                                |      |      |      |       |  |
|--------------------------------------------------------------------------------------|----------------------------------|----------------------------------------------------------------|------|------|------|-------|--|
| PARAMETER                                                                            | SYMBOL                           | TEST CONDITIONS                                                | MIN. | TYP. | MAX. | UNITS |  |
| Breakdown voltage, blocking voltage                                                  | V <sub>BR</sub> , V <sub>R</sub> |                                                                | 600  | -    | -    |       |  |
|                                                                                      | V <sub>F</sub>                   | I <sub>F</sub> = 30 A                                          | -    | 1.36 | 1.6  | 7     |  |
| Forward voltage                                                                      |                                  | I <sub>F</sub> = 60 A                                          | -    | 1.6  | -    | V     |  |
|                                                                                      |                                  | I <sub>F</sub> = 30 A, T <sub>J</sub> = 125 °C                 | -    | 1.23 | -    |       |  |
|                                                                                      |                                  | I <sub>F</sub> = 60 A, T <sub>J</sub> = 125 °C                 | -    | 1.5  | -    |       |  |
|                                                                                      |                                  | I <sub>F</sub> = 30 A, T <sub>J</sub> = 150 °C                 | -    | 1.19 | 1.35 | ]     |  |
|                                                                                      |                                  | I <sub>F</sub> = 60 A, T <sub>J</sub> = 150 °C                 | -    | 1.48 | -    |       |  |
| Reverse leakage current                                                              | I <sub>R</sub>                   | V <sub>R</sub> = V <sub>R</sub> rated                          | -    | -    | 50   |       |  |
|                                                                                      |                                  | T <sub>J</sub> = 125 °C, V <sub>R</sub> = V <sub>R</sub> rated | -    | -    | 500  | μA    |  |
| Junction capacitance                                                                 | C <sub>T</sub>                   | V <sub>R</sub> = 600 V - 18.3 -                                |      | -    | pF   |       |  |



| <b>DYNAMIC RECOVERY CHARACTERISTICS</b> (T <sub>J</sub> = 25 °C unless otherwise specified) |                  |                         |                                                                                    |      |      |      |       |
|---------------------------------------------------------------------------------------------|------------------|-------------------------|------------------------------------------------------------------------------------|------|------|------|-------|
| PARAMETER                                                                                   | SYMBOL           | TEST CONDITIONS         |                                                                                    | MIN. | TYP. | MAX. | UNITS |
| Doverno recover time                                                                        | t <sub>rr</sub>  | T <sub>J</sub> = 25 °C  | I <sub>F</sub> = 30 A<br>dI <sub>F</sub> /dt = 1000 A/μs<br>V <sub>R</sub> = 400 V | -    | 65   | -    | ns    |
| Reverse recovery time                                                                       |                  | T <sub>J</sub> = 125 °C |                                                                                    | -    | 90   | -    |       |
| Deals was a summer t                                                                        | I <sub>RRM</sub> | T <sub>J</sub> = 25 °C  |                                                                                    | -    | 18   | -    | A     |
| Peak recovery current                                                                       |                  | T <sub>J</sub> = 125 °C |                                                                                    | -    | 32   | -    |       |
| Reverse recovery charge Q <sub>rr</sub>                                                     | 0                | T <sub>J</sub> = 25 °C  |                                                                                    | -    | 850  | -    | nC    |
|                                                                                             | Q <sub>rr</sub>  | T <sub>J</sub> = 125 °C |                                                                                    | -    | 1850 | -    | 110   |

| THERMAL - MECHANICAL SPECIFICATIONS   |                   |                        |      |       |        |                  |
|---------------------------------------|-------------------|------------------------|------|-------|--------|------------------|
| PARAMETER                             | SYMBOL            | TEST CONDITIONS        | MIN. | TYP.  | MAX.   | UNITS            |
| Thermal resistance, junction to case  | R <sub>thJC</sub> |                        | -    | -     | 1      | °C/W             |
| Thermal resistance, case to heat sink | R <sub>thCS</sub> |                        | ı    | 0.4   | -      |                  |
| Weight                                |                   |                        | 1    | 6.0   | -      | g                |
| Weight                                |                   |                        | ı    | 0.21  | -      | oz.              |
| Maunting toyang                       |                   |                        | 6.0  |       | 12     | kgf · cm         |
| Mounting torque                       |                   |                        | (5)  | _     | (10)   | (lbf $\cdot$ in) |
| Marking device                        |                   | Case style TO-247AD 3L |      | C4PU3 | 3006LH |                  |

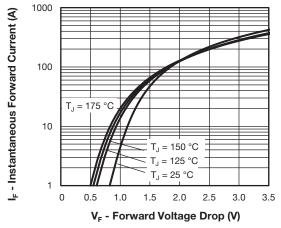


Fig. 1 - Typical Forward Voltage Drop Characteristics

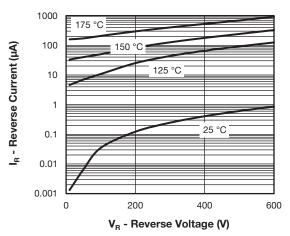


Fig. 2 - Typical Values of Reverse Current vs. Reverse Voltage

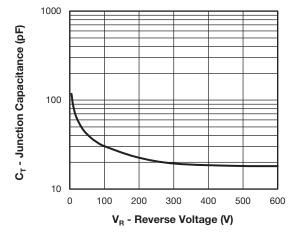


Fig. 3 - Typical Junction Capacitance vs. Reverse Voltage

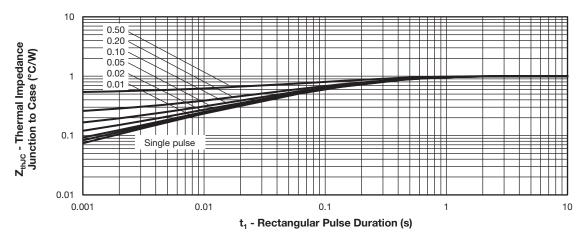


Fig. 4 - Maximum Thermal Impedance Z<sub>thJC</sub> Characteristics

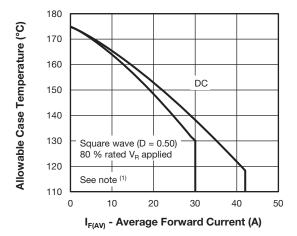


Fig. 5 - Maximum Allowable Case Temperature vs. Average Forward Current

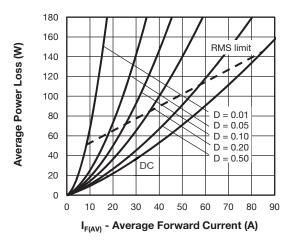


Fig. 6 - Forward Power Loss Characteristics

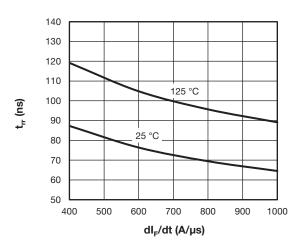


Fig. 7 - Typical Reverse Recovery Time vs.  $dI_F/dt$ 

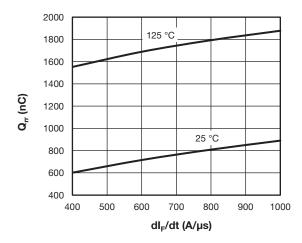


Fig. 8 - Typical Stored Charge vs. dl<sub>F</sub>/dt

#### Note

 $\begin{array}{ll} \text{(1)} & \text{Formula used: } T_C = T_J - (P_d + P_{dREV}) \times R_{thJC}; \\ Pd = \text{forward power loss} = I_{F(AV)} \times V_{FM} \text{ at } (I_{F(AV)}/D) \text{ (see Fig.5)} \\ P_{dREV} = \text{inverse power loss} = V_{R1} \times I_R \text{ (1 - D); } I_R \text{ at } V_R = \text{rated } V_R \\ \end{array}$ 

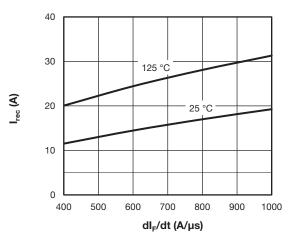
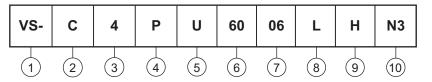


Fig. 9 - Typical Reverse Current vs. dl<sub>F</sub>/dt

#### **ORDERING INFORMATION TABLE**

**Device code** 



- 1 Vishay Semiconductors product
- **2** Circuit configuration:

C = common diode

- FRED Pt Gen 4
- P = TO-247 package
- **5** Process type:

U = ultrafast recovery

- 6 Current rating (60 = 2 x 30 A)
- 7 Voltage rating (06 = 600 V)
- 8 Package: L = long lead
- 9 H = AEC-Q101 qualified
- 10 Environmental digit:

N3 = halogen-free, RoHS-compliant, and totally lead (Pb)-free

| ORDERING INFORMATION (Example) |                                                               |     |                         |  |  |
|--------------------------------|---------------------------------------------------------------|-----|-------------------------|--|--|
| PREFERRED P/N                  | QUANTITY PER TUBE MINIMUM ORDER QUANTITY PACKAGING DESCRIPTIO |     |                         |  |  |
| VS-C4PU6006LHN3                | 25                                                            | 500 | Antistatic plastic tube |  |  |

| LINKS TO RELATED DOCUMENTS                             |             |                          |  |  |  |
|--------------------------------------------------------|-------------|--------------------------|--|--|--|
| Dimensions TO-247AD 3L <u>www.vishay.com/doc?95626</u> |             |                          |  |  |  |
| Part marking information                               | TO-247AD 3L | www.vishay.com/doc?95007 |  |  |  |



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